L Number	Hits	Search Text	DB	Time stamp
12	1290	445/3,24.ccls.	USPAT;	2003/06/14 13:5:
			US-PGPUB	
13	10	445/3,24.ccls. and ((light near2 (emitting emission emitter) near2	USPAT;	2003/06/14 13:5
		(dispalay device panel)) LED ((EL electroluminescen\$2) near2	US-PGPUB	
		(display device panel))) and (electrode cathode anode) and (xray		
		x-ray (x near2 ray) (electromagnetic near2 (field charge energy		
		wave source))) and (measurement measur\$3 detect\$3 inspect\$3		
		test\$3)		
15	7	438/10,14-17.ccls. and ((light near2 (emitting emission emitter)	USPAT;	2003/06/14 14:0
16		near2 (dispalay device panel)) LED ((EL electroluminescen\$2)	US-PGPUB	
		near2 (display device panel))) and (electrode cathode anode) and		
		((xray x-ray (x near2 ray) electromagnetic) near2 (field charge		
		energy wave source)) and (measurement measur\$3 detect\$3]	
	26	inspect\$3 test\$3)	LICOAT	2002/06/44 44
16	36	324/500-537,750-765.ccls. and ((light near2 (emitting emission	USPAT;	2003/06/14 14:1
		emitter) near2 (dispalay device panel)) LED ((EL	US-PGPUB	
		electroluminescen\$2) near2 (display device panel))) and (electrode cathode anode) and ((xray x-ray (x near2 ray)		
		electromagnetic) near2 (field charge energy wave source)) and		
		(measurement measur\$3 detect\$3 inspect\$3 test\$3)		
17	25	((light near2 (emitting emission emitter) near2 (dispalay device	EPO; JPO;	2003/06/14 17:3
1		panel)) LED ((EL electroluminescen\$2) near2 (display device	DERWENT	2003/00/14 17.3
		panel))) and (electrode cathode anode) and ((xray x-ray (x near2	DERWEIT	
		ray) electromagnetic) near2 (field charge energy wave source))		
		and (measurement measur\$3 detect\$3 inspect\$3 test\$3)		
18	416	(445/\$.ccls. 324/\$.ccls. 438/\$.ccls.) and ((substrate	USPAT;	2003/06/14 17:2
į		semiconductor) same (electrode cathode anode)) and ((xray x-ray	US-PGPUB	
		(x near2 ray) electromagnetic) near2 (field charge energy wave		
		source)) and ((measurement measur\$3 detect\$3 inspect\$3 test\$3)		
		with (voltage current power (electric near2 field)))		
19	12	5103182.URPN.	USPAT	2003/06/14 14:5
20	5	("4704576" "4767982" "4818930" "4866370"	USPAT	2003/06/14 14:5
	_	"4868490").PN.		
21	2 7	5897378.URPN.	USPAT	2003/06/14 16:3
22	/	("4430151" "4902631" "4975141" "5082517" "5215588"	USPAT	2003/06/14 16:3
23	2	"5536359" "5770097").PN.	LICDAT	2002/06/4 4 7 4
24	3 0	("3715667" "4634963" "5424633").PN. 6320401.URPN.	USPAT	2003/06/14 17:10
25	331-		USPAT	2003/06/14 17:10
- 25	551	semiconductor) same (electrode cathode anode)) and ((xray x-ray	USPAT;US-PGPUB	2003/06/14_17:3
		(x near2 ray) electromagnetic) near2 (field charge energy wave	03-70708	
		source)) and ((measurement measur\$3 detect\$3 inspect\$3 test\$3)		
		with (voltage current power (electric near2 field)))) not		
İ		@ad>20010530		
26	662	438/17.ccls.	USPAT;	2003/06/14 17:34
		·	US-PGPUB	,,,
27	81	438/17.ccls. and (electrode cathode anode) and ((xray x-ray	USPAT;	2003/06/14 17:39
		electron light laser (x near2 ray) electromagnetic) near2 (field	US-PGPUB	
		charge beam energy wave source)) and (measurement measur\$3		
		detect\$3 inspect\$3 test\$3)		
28	76	438/17.ccls. and (electrode cathode anode) and ((xray x-ray	USPAT;	2003/06/14 17:5
		electron light laser (x near2 ray) electromagnetic) near2 (field	US-PGPUB	
		charge beam energy wave source)) and ((measurement measur\$3		
20		detect\$3 inspect\$3 test\$3) same (current voltage electric\$3))		
30	466	((xray x-ray electron light laser (x near2 ray) electromagnetic)	USPAT;	2003/06/14 18:04
		near2 (field charge beam energy wave source)) and	US-PGPUB	
		((measurement measur\$3 detect\$3 inspect\$3 test\$3) same	İ	
		(current voltage electric\$3)) and ((gas gaseous) with ioniz\$3) and		
20	ee.	(445/\$.ccls. 438/\$.ccls. 257/\$.ccls. 324/\$.ccls.)	EDG 355	inana tagu
29	55	((xray x-ray electron light laser (x near2 ray) electromagnetic)	EPO; JPO;	2003/06/14 18:20
		near2 (field charge beam energy wave source)) and	DERWENT	i
	•	((measurement measur\$3 detect\$3 inspect\$3 test\$3) same (current voltage electric\$3)) and ((gas gaseous) with ioniz\$3)		
		(Content voltage electricas)) and ((gas gaseous) with ionizas)	L	<u> </u>

31	369	((xray x-ray electron light laser (x near2 ray) electromagnetic)	USPAT;	2003/06/14 18:05
J1	309	near2 (field charge beam energy wave source)) and	US-PGPUB	2003/00/14 10.03
		((measurement measur\$3 detect\$3 inspect\$3 test\$3) same	05 1 01 05	
		(current voltage electric\$3)) and ((gas gaseous) with ioniz\$3) and		
		(445/\$.ccls. 438/\$.ccls. 324/\$.ccls.)		
14	10	1	USPAT;	2003/06/14 18:24
		near2 (dispalay device panel)) LED ((EL electroluminescen\$2)	US-PGPUB	2000,00,1120,21
		near2 (display device panel))) and (electrode cathode anode)	00 1 01 05	
		and (xray x-ray (x near2 ray) (electromagnetic near2 (field charge		
		energy wave source))) and (measurement measur\$3 detect\$3		
		inspect\$3 test\$3)		
35	780	TFT same (measurement measur\$3 detect\$3 inspect\$3 test\$3)	EPO; JPO;	2003/06/14 18:20
			DERWENT	
36	387	TFT same (measurement measur\$3 detect\$3 inspect\$3 test\$3)	EPO; JPO;	2003/06/14 18:24
		same (display device)	DERWENT	
37	48	TFT same (measurement measur\$3 detect\$3 inspect\$3 test\$3)	EPO; JPO;	2003/06/14 18:26
		same (display device) and ((xray x-ray electron light laser (x near2	DERWENT	
		ray) electromagnetic) near2 (field charge beam energy wave		
		source))		
38	141	TFT same (measurement measur\$3 detect\$3 inspect\$3 test\$3)	USPAT;	2003/06/14 18:50
		same (display device) and ((xray x-ray electron light laser (x near2	US-PGPUB	
		ray) electromagnetic) near2 (field charge beam energy wave		
		source)) and (445/\$.ccls. 438/\$.ccls. 324/\$.ccls.)		
39	1	5982190.URPN.	USPAT	2003/06/14 18:39
40	4	("5276400" "5371459" "5432461" "5504438").PN.	USPAT	2003/06/14 18:40
41	1	TFT same ((measurement measur\$3 detect\$3 inspect\$3 test\$3)	USPAT;	2003/06/14 18:52
		with (current voltage electric electrical)) same (ioniz\$3) and	US-PGPUB	
42	228	(445/\$.ccls. 438/\$.ccls. 324/\$.ccls.)	LICDAT	2002/06/44 40 50
42	220	(((managed and a contract and a con	USPAT;	2003/06/14 18:59
		(current voltage electric electrical)) same (ioniz\$3)) and (445/\$.ccls. 438/\$.ccls. 324/\$.ccls.) and (TFT electrode) and	US-PGPUB	
		(display device panel)		
43	264	semiconductor and (EL electroluminescent (light near2 (emitting	USPAT;	2003/06/14 19:35
13	201	emission emitter))) and electrode and (inspect\$3 same substrate)	US-PGPUB	2003/00/14 13:33
44	175	(semiconductor same (TFT electrode)) and (EL electroluminescent	USPAT;	2003/06/14 19:36
•	1,3	(light near2 (emitting emission emitter))) and (inspect\$3 same	US-PGPUB	2003/00/17 13.30
		substrate)	03 1 01 05	